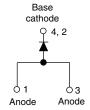


Vishay Semiconductors

Schottky Rectifier, 3.5 A





| ו-ח | DΛK | /TO | -252 | 4 4 1 |
|-----|-----|-----|------|--------------|
| | | | | |

| PRODUCT SUMMARY | | | | |
|----------------------------------|----------------------|--|--|--|
| Package | D-PAK (TO-252AA) | | | |
| I _{F(AV)} | 3.5 A | | | |
| V _R | 100 V | | | |
| V _F at I _F | See Electrical table | | | |
| I _{RM} | 4.9 mA at 125 °C | | | |
| T _J max. | 150 °C | | | |
| Diode variation | Single die | | | |
| E _{AS} | 5 mJ | | | |

FEATURES

- Popular D-PAK outline
- Small foot print, surface mountable



- · Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- \bullet Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\text{C}$

DESCRIPTION

The VS-30WQ10FNPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | |
|-----------------------------------|--------------------------------|-------------|-------|--|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | | |
| I _{F(AV)} | Rectangular waveform | 3.5 | A | | | | |
| V_{RRM} | | 100 | V | | | | |
| I _{FSM} | t _p = 5 μs sine | 440 | A | | | | |
| V _F | 3 Apk, T _J = 125 °C | 0.63 | V | | | | |
| T _J | | - 40 to 150 | °C | | | | |

| VOLTAGE RATINGS | | | | | | |
|---------------------------------------|-----------|-----|---|--|--|--|
| PARAMETER SYMBOL VS-30WQ10FNPbF UNITS | | | | | | |
| Maximum DC reverse voltage | V_{R} | 100 | V | | | |
| Maximum working peak reverse voltage | V_{RWM} | 100 | V | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|---|--------------------|---|---|-------|----|--|--|
| PARAMETER | SYMBOL | TEST COND | VALUES | UNITS | | | |
| Maximum average forward current See fig. 5 | I _{F(AV)} | 50 % duty cycle at T _C = 135 °C | , rectangular waveform | 3.5 | | | |
| Maximum peak one cycle non-repetitive surge current | l=o | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and with rated | 440 | Α | | |
| See fig. 7 | IFSM | 10 ms sine or 6 ms rect. pulse | V _{RRM} applied | 70 | | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 1 A, L = 10 mH | | 5.0 | mJ | | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 µs Frequency limited by T _J maximum V _A = 1.5 x V _B typical | | 0.5 | Α | | |

VS-30WQ10FNPbF

Vishay Semiconductors

Schottky Rectifier, 3.5 A



Document Number: 94200

Revision: 14-Jan-11

| ELECTRICAL SPECIFICATIONS | | | | | | | | |
|---------------------------------|--------------------------------|---|---------------------------------------|--------|------|--|--|--|
| PARAMETER | SYMBOL | TEST COND | VALUES | UNITS | | | | |
| | | 3 A | T _{.1} = 25 °C | 0.81 | V | | | |
| Maximum forward voltage drop | V _{FM} ⁽¹⁾ | 6 A | 11 = 23 0 | 0.96 | | | | |
| See fig. 1 | VFM (') | 3 A | T _{.1} = 125 °C | 0.63 | | | | |
| | | 6 A | 1j = 125 C | 0.74 | | | | |
| Maximum reverse leakage current | I _{RM} ⁽¹⁾ | T _J = 25 °C | V Data d V | 1 | mA | | | |
| See fig. 2 | IRM (**) | T _J = 125 °C | V _R = Rated V _R | 4.9 | | | | |
| Threshold voltage | V _{F(TO)} | T - T movimum | | 0.48 | V | | | |
| Forward slope resistance | r _t | $T_J = T_J$ maximum | | 30.89 | mΩ | | | |
| Typical junction capacitance | C _T | V _R = 5 V _{DC} (test signal range | 92 | pF | | | | |
| Typical series inductance | L _S | Measured lead to lead 5 mm | 5.0 | nH | | | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | _ | 10 000 | V/µs | | | |

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|--|--|--|-------------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | |
| Maximum junction and storage temperature range | T _J ⁽¹⁾ , T _{Stg} | | - 40 to 150 | °C | | | |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation See fig. 4 | 4.7 | °C/W | | | |
| Approximate weight | | | 0.3 | g | | | |
| Approximate weight | | | 0.01 | oz. | | | |
| Marking device | | Case style D-PAK (similar to TO-252AA) | 30WC | 10FN | | | |

Note

 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$



Schottky Rectifier, 3.5 A

Vishay Semiconductors

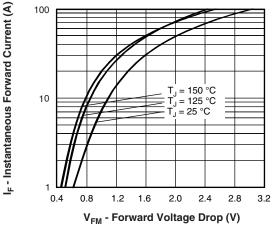


Fig. 1 - Maximum Forward Voltage Drop Characteristics

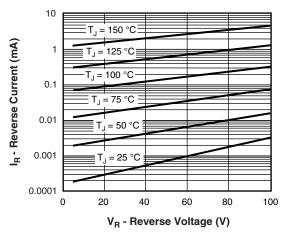


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

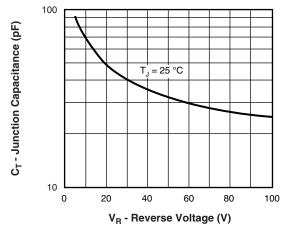


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

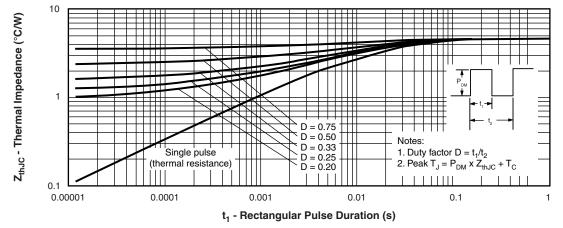
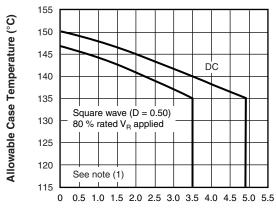


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Vishay Semiconductors

Schottky Rectifier, 3.5 A





 $I_{F(AV)}$ - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

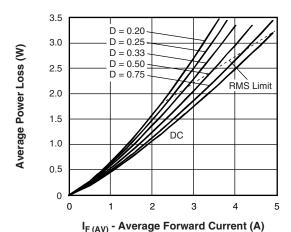


Fig. 6 - Forward Power Loss Characteristics

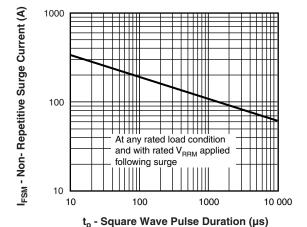


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% rated } V_R \text{ (1 - D); } I_R \text{ (2 - D); } I_R \text{ (3 - D); } I_R \text{ (2 - D); } I_R \text{ (3 - D); } I_R \text{ (3 - D); } I_R \text{ (4 - D);$

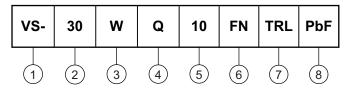


Schottky Rectifier, 3.5 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (3.5 A)

Package identifier:

W = D-PAK

4 - Schottky "Q" series

5 - Voltage rating (10 = 100 V)

6 - FN = TO-252AA (D-PAK)

7 • None = Tube (50 pieces)

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

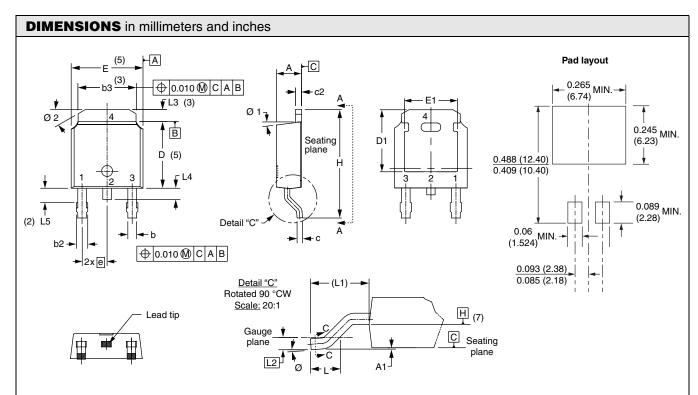
PbF = Lead (Pb)-free

| LINKS TO RELATED DOCUMENTS | | | | |
|--|--------------------------|--|--|--|
| Dimensions <u>www.vishay.com/doc?95016</u> | | | | |
| Part marking information | www.vishay.com/doc?95059 | | | |
| Packaging information | www.vishay.com/doc?95033 | | | |



Vishay High Power Products

D-PAK (TO-252AA)



| SYMBOL | MILLIM | ETERS | INC | HES | NOTES | |
|--------|--------|-------|-------|-------|-------|--|
| | MIN. | MAX. | MIN. | MAX. | NOTES | |
| Α | 2.18 | 2.39 | 0.086 | 0.094 | | |
| A1 | - | 0.13 | - | 0.005 | | |
| b | 0.64 | 0.89 | 0.025 | 0.035 | | |
| b2 | 0.76 | 1.14 | 0.030 | 0.045 | | |
| b3 | 4.95 | 5.46 | 0.195 | 0.215 | 3 | |
| С | 0.46 | 0.61 | 0.018 | 0.024 | | |
| c2 | 0.46 | 0.89 | 0.018 | 0.035 | | |
| D | 5.97 | 6.22 | 0.235 | 0.245 | 5 | |
| D1 | 5.21 | - | 0.205 | 1 | 3 | |
| Е | 6.35 | 6.73 | 0.250 | 0.265 | 5 | |
| E1 | 4.32 | - | 0.170 | - | 3 | |

| SYMBOL | MILLIMETERS | | INC | NOTES | |
|--------|-------------|-------|-------|-------|-------|
| STWBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| е | 2.29 | BSC | 0.090 | BSC | |
| Н | 9.40 | 10.41 | 0.370 | 0.410 | |
| L | 1.40 | 1.78 | 0.055 | 0.070 | |
| L1 | 2.74 | BSC | 0.108 | REF. | |
| L2 | 0.51 BSC | | 0.020 | BSC | |
| L3 | 0.89 | 1.27 | 0.035 | 0.050 | 3 |
| L4 | - | 1.02 | - | 0.040 | |
| L5 | 1.14 | 1.52 | 0.045 | 0.060 | 2 |
| Ø | 0° | 10° | 0° | 10° | |
| Ø1 | 0° | 15° | 0° | 15° | |
| Ø2 | 25° | 35° | 25° | 35° | |

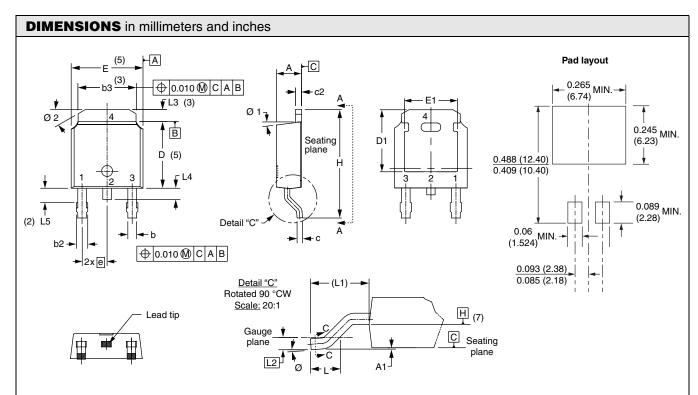
Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- $^{(7)}$ Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



Vishay High Power Products

D-PAK (TO-252AA)



| SYMBOL | MILLIM | ETERS | INC | HES | NOTES | |
|--------|--------|-------|-------|-------|-------|--|
| | MIN. | MAX. | MIN. | MAX. | NOTES | |
| Α | 2.18 | 2.39 | 0.086 | 0.094 | | |
| A1 | - | 0.13 | - | 0.005 | | |
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| С | 0.46 | 0.61 | 0.018 | 0.024 | | |
| c2 | 0.46 | 0.89 | 0.018 | 0.035 | | |
| D | 5.97 | 6.22 | 0.235 | 0.245 | 5 | |
| D1 | 5.21 | - | 0.205 | - | 3 | |
| Е | 6.35 | 6.73 | 0.250 | 0.265 | 5 | |
| E1 | 4.32 | - | 0.170 | - | 3 | |

| SYMBOL | MILLIMETERS | | INC | NOTES | |
|--------|-------------|-------|-------|-------|-------|
| STWBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| е | 2.29 | BSC | 0.090 | BSC | |
| Н | 9.40 | 10.41 | 0.370 | 0.410 | |
| L | 1.40 | 1.78 | 0.055 | 0.070 | |
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| L2 | 0.51 BSC | | 0.020 | BSC | |
| L3 | 0.89 | 1.27 | 0.035 | 0.050 | 3 |
| L4 | - | 1.02 | - | 0.040 | |
| L5 | 1.14 | 1.52 | 0.045 | 0.060 | 2 |
| Ø | 0° | 10° | 0° | 10° | |
| Ø1 | 0° | 15° | 0° | 15° | |
| Ø2 | 25° | 35° | 25° | 35° | |

Notes

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- (8) Outline conforms to JEDEC outline TO-252AA



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